

#### **Features**

- High Dense Cell Design for Extremely Low R<sub>DS(ON)</sub>
- · Exceptional On-Resistance and Maximum DC Current Capability
- · Epoxy Meets UL 94 V-0 Flammability Rating
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

# **N-Channel MOSFET**

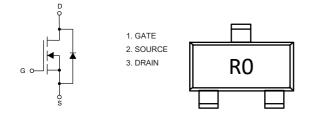
## **Maximum Ratings**

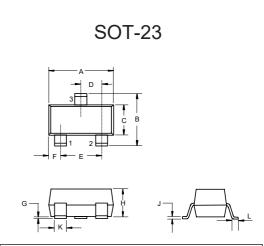
- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 357°C/W Junction to Ambient(Note 3)

Parameter	Symbol	Rating	Unit
Drain -Source Voltage	V <sub>DS</sub>	30	V
Gate -Source Voltage	$V_{GS}$	±12	V
Drain Current-Continuous	I <sub>D</sub>	5.8	Α
Drain Current-Pulsed (Note 2)	I <sub>DM</sub>	30	Α
Power Dissipation	P <sub>D</sub>	0.35	W

Note: 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

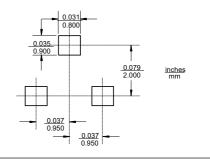
# **Internal Structure and Marking Code**





DIMENSIONS						
DIM	INCHES		MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	NOTE	
Α	0.110	0.120	2.80	3.04		
В	0.083	0.104	2.10	2.64		
С	0.047	0.055	1.20	1.40		
D	0.034	0.041	0.85	1.05		
E	0.067	0.083	1.70	2.10		
F	0.018	0.024	0.45	0.60		
G	0.0004	0.006	0.01	0.15		
Н	0.035	0.043	0.90	1.10		
J	0.003	0.007	0.08	0.18		
K	0.012	0.020	0.30	0.51		
L	0.007	0.020	0.20	0.50		

#### **Suggested Solder Pad Layout**





## **ELECTRICAL CHARACTERISTICS (Ta=25℃ unless otherwise specified)**

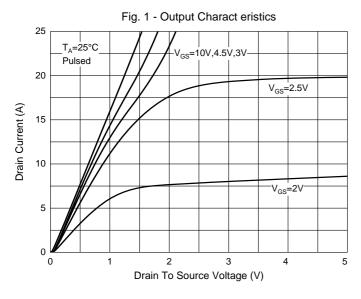
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Static Characteristics	1		<u> </u>	1	I	
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	30			V
Gate-Threshold Voltage <sup>(Note 4)</sup>	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	0.7		1.4	٧
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =± 12V, V <sub>DS</sub> =0V			±100	nA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =24V, V <sub>GS</sub> =0V			1	μA
	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =5.8A			35	
Drain-Source On-Resistance <sup>(Note 4)</sup>		V <sub>GS</sub> =4.5V, I <sub>D</sub> =5.0A			40	$\boldsymbol{m}\Omega$
		$V_{GS}$ =2.5V, $I_{D}$ =4.0A			52	
Forward Transconductance	<b>g</b> FS	$V_{DS}$ =5V, $I_{D}$ =5.0A	8.0			S
Dynamic Characteristics(Note 5)						
Total Gate Charge	$Q_g$			17.25		
Gate-Source Charge	$Q_{gs}$	V <sub>GS</sub> =10V,V <sub>DS</sub> =15V, I <sub>D</sub> =5.6A		2.1		nC
Gate-Drain Charge	$Q_{gd}$			2		
Input Capacitance	C <sub>iss</sub>				1050	
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =15V,V <sub>GS</sub> =0V, f=1MHz		99		pF
Reverse Transfer Capacitance	C <sub>rss</sub>			77		
Gate Resistance	$R_g$	V <sub>DS</sub> =0V,V <sub>GS</sub> =0V,f =1MHz			3.6	Ω
Switching Characteristics(Note	5)		'		1	
Turn-On Delay Time	t <sub>d(on)</sub>				5	
Turn-On Rise Time	t <sub>r</sub>	$V_{GS}$ =10V,R <sub>L</sub> =2.7 $\Omega$ ,V <sub>DS</sub> =15V,			7	
Turn-Off Delay Time	t <sub>d(off)</sub>	$R_{GEN}$ =3 $\Omega$			40	ns
Turn-Off Fall Time	t <sub>f</sub>				6	
Drain-Source Diode Characte	ristics an	d Maximum Ratings		-	I	
Diode Forward voltage <sup>(Note 4)</sup>	V <sub>SD</sub>	$V_{GS}$ =0V, $I_{S}$ =1A			1.0	V

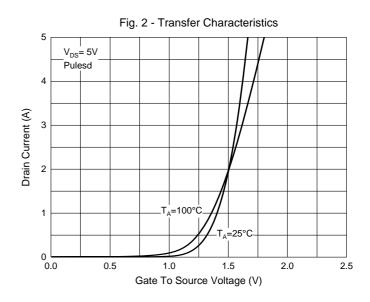
### Notes:

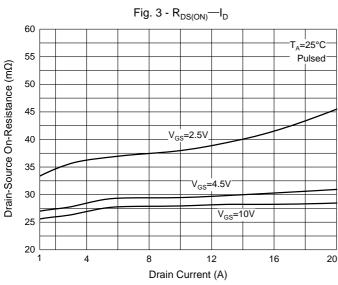
- 2. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 3. Surface Mounted on FR4 Board, t < 5 sec.
- 4. Pulse Test: Pulse Width≤300μA, Duty Cycle≤2%.5. Guaranteed by Design, Not Subject to Production Testing.

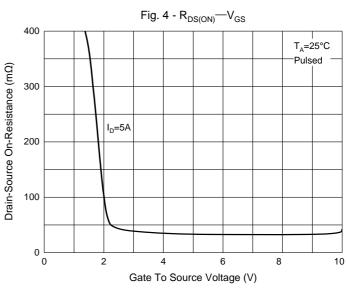


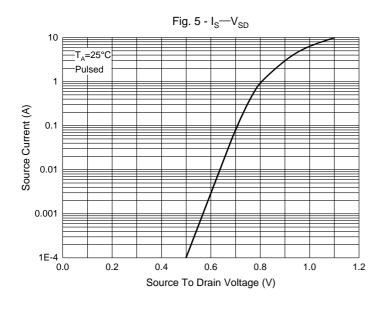
### **Curve Characteristics**

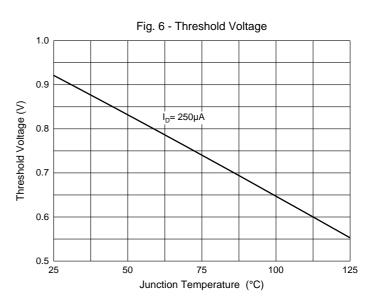














## **Ordering Information**

Device	Packing
Part Number-TP	Tape&Reel:3Kpcs/Reel

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